

**Phase-out/Discontinued**

**DESCRIPTION** The 2SK719 is N-channel MOS Field Effect Power Transistor designed for switching power supplies, DC-DC converters.

**FEATURES**

- Suitable for switching power supplies, actuator controls, and pulse circuits.
- Low  $R_{DS(on)}$
- No second breakdown

**ABSOLUTE MAXIMUM RATINGS**

Maximum Temperatures

Storage Temperature . . . . . -55 to +150 °C

Channel Temperature . . . . . 150 °C Maximum

Maximum Power Dissipation ( $T_a = 25^\circ\text{C}$ )

Total Power Dissipation . . . . . 120 W

Maximum Voltages and Currents ( $T_a = 25^\circ\text{C}$ )

$V_{DSS}$  Drain to Source Voltage . . . . . 900 V

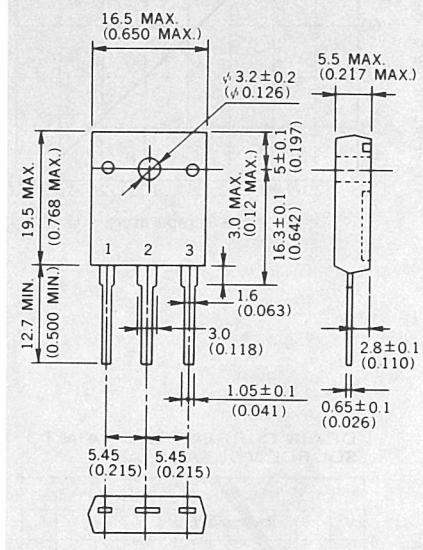
$V_{GSS}$  Gate to Source Voltage . . . . .  $\pm 20$  V

$I_{D(\text{DC})}$  Drain Current (DC) . . . . .  $\pm 5$  A

$I_{D(\text{pulse})}$  Drain Current (pulse)\* . . . . .  $\pm 10$  A

\* PW  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2\%$

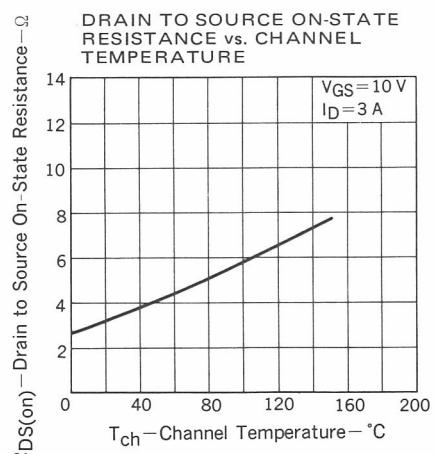
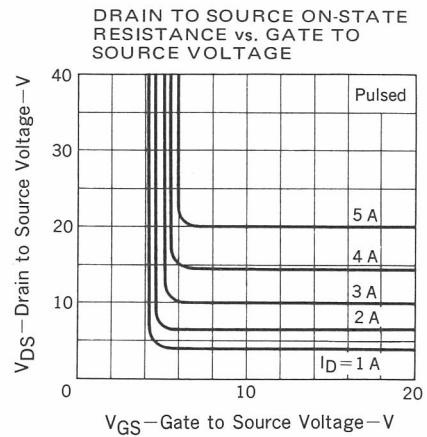
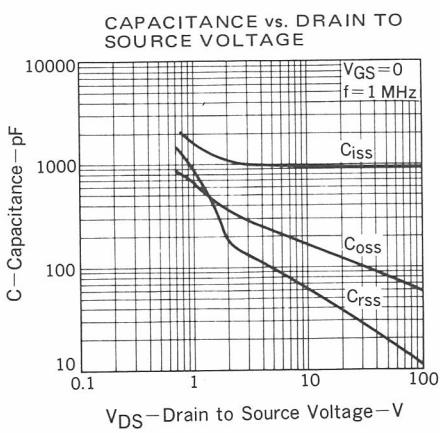
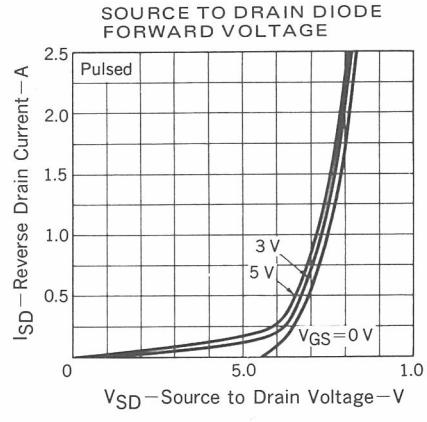
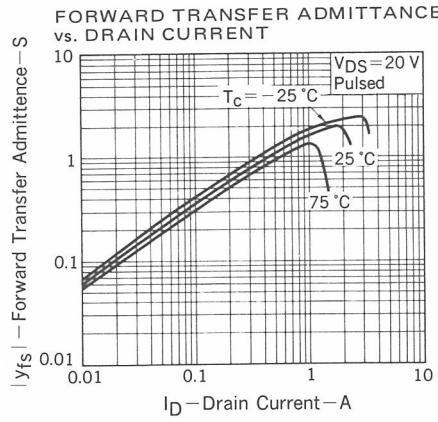
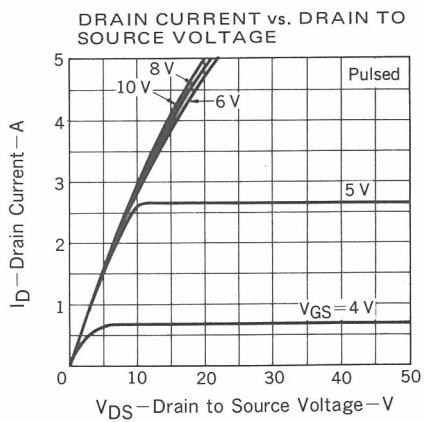
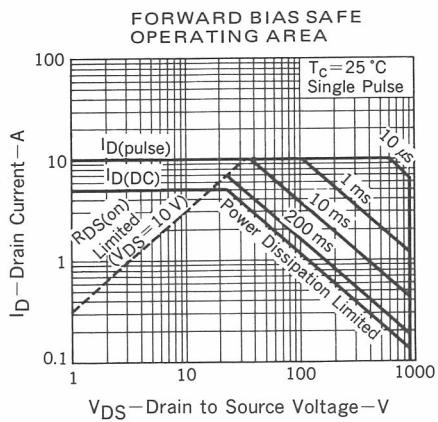
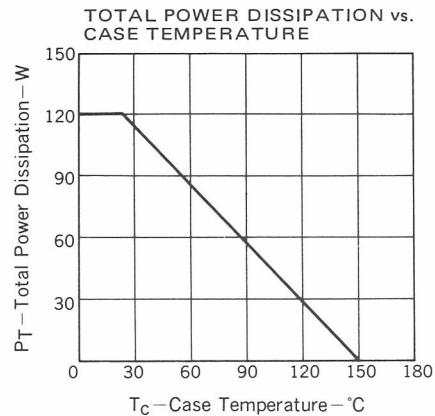
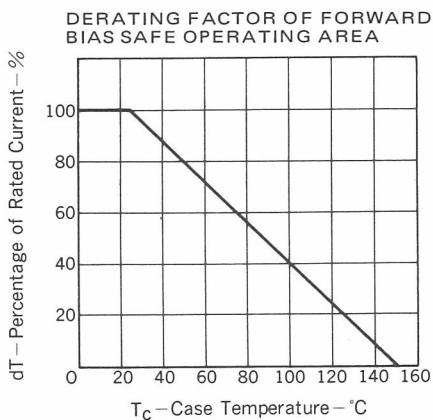
**PACKAGE DIMENSIONS**  
in millimeters (inches)



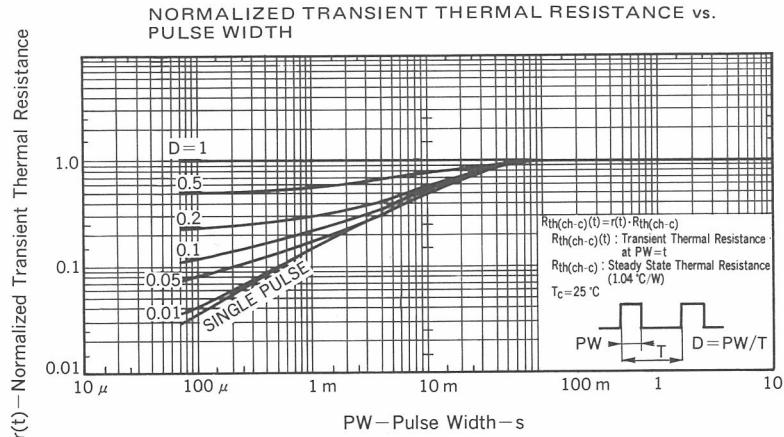
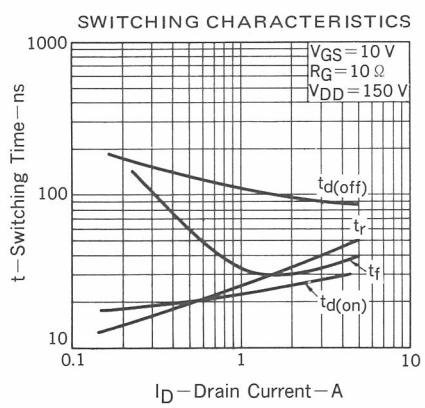
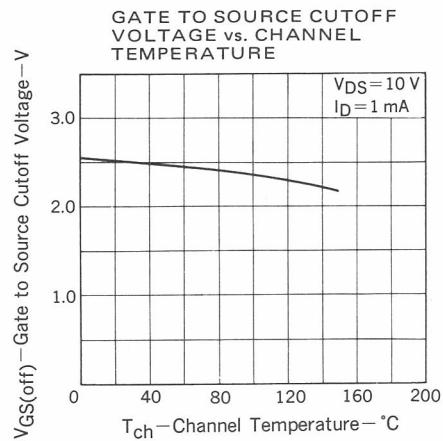
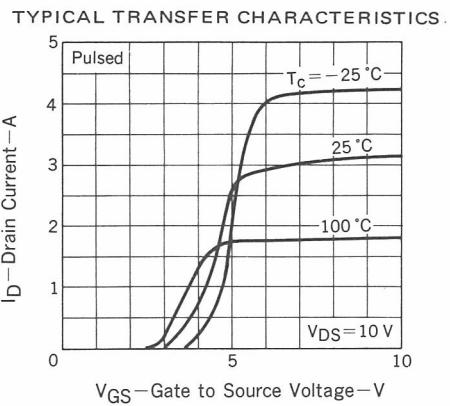
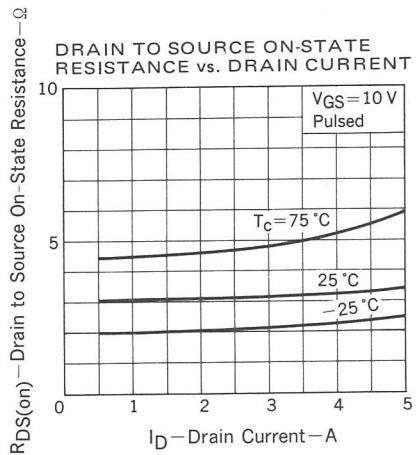
1. Gate
2. Drain (Fin)
3. Source

**ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )**

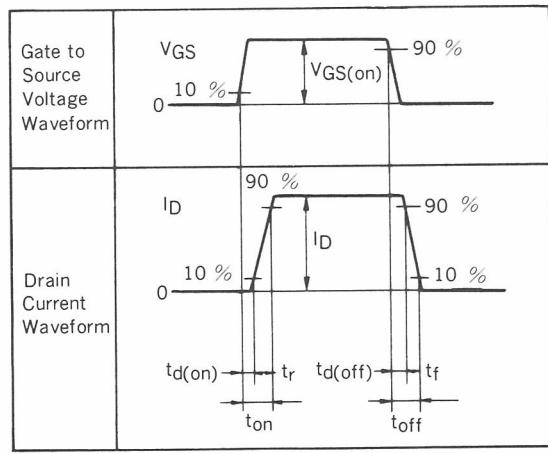
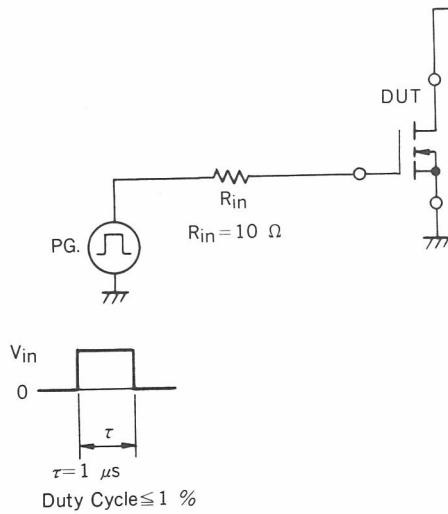
SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
$I_{DSS}$	Drain Leakage Current			100	$\mu\text{A}$	$V_{DS} = 900 \text{ V}, V_{GS} = 0$
$I_{GSS}$	Gate to Source Leakage Current			$\pm 100$	nA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
$V_{GS(\text{off})}$	Gate to Source Cutoff Voltage	1.5		3.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
$ Y_{fs} $	Forward Transfer Admittance	1.0	2.5		S	$V_{DS} = 10 \text{ V}, I_D = 3 \text{ A}$
$R_{DS(\text{on})}$	Drain to Source On-State Resistance		3.2	4.0	$\Omega$	$V_{GS} = 10 \text{ V}, I_D = 3 \text{ A}$
$C_{iss}$	Input Capacitance		950		pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$
$C_{oss}$	Output Capacitance		170		pF	
$C_{rss}$	Reverse Transfer Capacitance		65		pF	
$t_{d(\text{on})}$	Turn-On Delay Time		15		ns	$I_D = 3 \text{ A}, V_{DD} = 150 \text{ V}$ $V_{GS(\text{on})} = 10 \text{ V}$ $R_L = 50 \Omega$ $R_{in} = 10 \Omega$
$t_r$	Rise Time		40		ns	
$t_{d(\text{off})}$	Turn-Off Delay Time		80		ns	
$t_f$	Fall Time		20		ns	

**Phase-out/Discontinued****TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )**

**Phase-out/Discontinued**



### SWITCHING TIME TEST CIRCUIT



2SK719

NEC ELECTRON DEVICE

**Phase-out/Discontinued**